

450MHz Band LNA GaAs MMIC

■ GENERAL DESCRIPTION

NJG1128HB6 is a LNA IC designed for 450MHz band CDMA cellular phone. This IC has the function which bypasses LNA, and high gain mode or low gain mode can be chosen.

High IIP3 and a low noise are achieved at the High gain mode. And low current consumption can be achieved at the low gain mode because LNA enters the state of the standby.

A small and thin package of USB8 is adopted.

■ PACKAGE OUTLINE



NJG1128HB6

■ FEATURES

Low voltage operation +2.8V typ.
Low control voltage operation +1.85V typ.

[LNA High Gain Mode]

High Input IP3 +11.0dBm typ. @ f=460-470MHz
Low noise figure 1.4dB typ. @ f=460-470MHz

[LNA Low Gain Mode]

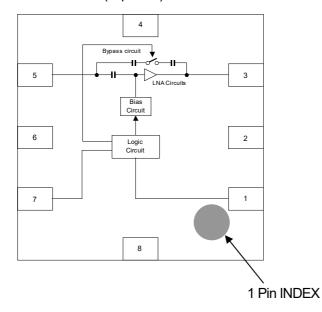
• Low current consumption 15uA typ.

● High Input IP3 +21.0dBm typ. @ f=460-470MHz

• Small & thin package USB8-B6 (Package size: 1.5mm x1.5mm x 0.55mm typ.)

■ PIN CONFIGURATION





Pin Connection

 $1.V_{INV}$

2.GND

3.RF OUT

4.GND

5.RF IN

6.GND

7. V_{CTL}

8. GND

Note: Specifications and description listed in this catalog are subject to change without prior notice.

■ ABSOLUTE MAXIMUM RATINGS

 $(T_a=+25^{\circ}C, Z_s=Z_l=50\Omega)$

PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Supply voltage	V_{DD}		5.0	V
Inverter supply voltage	V _{INV}		5.0	V
Control voltage	V _{CTL}		5.0	V
Input power	Pin		+15	dBm
Power dissipation	P _D	on PCB board, at Tjmax=150°C	160	mW
Operating temperature	T _{opr}		-40~+85	°C
Storage temperature	T _{stg}		-55~+150	°C

■ ELECTRICAL CHARACTERISTICS 1 (DC CHARACTERISTICS)

(General Conditions: $V_{DD}=V_{INV}=2.8V$, $T_a=+25^{\circ}C$, $Z_s=Z_I=50\Omega$)

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating voltage	V_{DD}		2.65	2.80	2.95	V
Inverter supply voltage	V _{INV}		2.65	2.80	2.95	V
Control voltage (High)	V _{CTL} (H)		1.80	1.85	V _{DD+} 0.3	V
Control voltage (Low)	V _{CTL} (L)		-0.3	0	0.3	V
Operating current1 (LNA High Gain Mode)	I _{DD} 1	RF OFF, V _{CTL} =1.85V	-	10.0	16.0	mA
Operating current2 (LNA Low Gain Mode)	I _{DD} 2	RFOFF, V _{CTL} =0V	-	1	5	uA
Inverter current1 (LNA High Gain Mode)	I _{INV} 1	RF OFF, V _{CTL} =1.85V	-	150	240	uA
Inverter current2 (LNA Low Gain Mode)	I _{INV} 2	RF OFF, V _{CTL} =0V	-	15	40	uA
Control current	I _{CTL}	RF OFF, V _{CTL} =1.85V	-	5	15	uA

■ ELECTRICAL CHARACTERISTICS 2 (LNA High Gain Mode)

(General Conditions: $V_{DD}=V_{INV}=2.8V$, $V_{CTL}=1.85V$, $f_{RF}=460-470MHz$, $T_a=+25^{\circ}C$, $Z_s=Z_I=50\Omega$)

,						
PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small signal gain1	Gain1			15.0	17.0	dB
Noise figure1	NF1	Exclude PCB & connector losses	-	1.4	1.8	dB
1dB gain compression output power1	P-1dB_1		+4.0	+9.0	1	dBm
3rd order Input Intercept Point1	IIP3_1	$f1=f_{RF}$, $f2=f_{RF}+100$ kHz, $P_{in}=-25$ dBm	+8.0	+11.0	1	dBm
RF IN VSWR1	VSWR _i _1		ı	1.5	2.0	
RF OUT VSWR1	VSWR _{o_} 1		_	2.3	2.7	

■ ELECTRICAL CHARACTERISTICS 3 (LNA Low Gain Mode)

(General Conditions: $V_{DD}=V_{INV}=2.8V$, $V_{CTL}=0V$, $f_{RF}=460-470MHz$, $T_a=+25^{\circ}C$, $Z_s=Z_I=50\Omega$)

(Concide Conditions: VDD VINV 2.5V, VCIE 6V, IRF 400 47 61VII 12, Ta 120 G, 2s Zi					, = 0011/	
PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Small signal gain2	Gain2		-5.0	-3.0	0	dB
Noise figure2	NF2	Exclude PCB & connector losses	-	3.0	4.5	dB
1dB gain compression output power2	P-1dB_2		+1.0	+8.0	-	dBm
3rd order Input Intercept Point2	IIP3_2	$f1=f_{RF}$, $f2=f_{RF}+100$ kHz, $P_{in}=-12$ dBm	+15.0	+21.0	1	dBm
RF IN VSWR2	VSWR _i _2		-	2.3	2.7	
RF OUT VSWR2	VSWR _{o_2}		-	1.5	2.0	

■ TERMINAL INFOMATION

No.	SYMBOL	DESCRIPTION
1	VINV	Supply voltage terminal for internal logic circuit (inverter).
2	GND	Ground terminal.
3	RFOUT	RF signal comes out from this terminal, and goes through an external matching circuit connected to this. Inductor L3 as shown in the application circuit is a part of an external matching circuit, and also provide DC power to LNA. Capacitor C3 as shown in the application circuit is a bypass capacitor.
4	GND	Ground terminal.
5	RFIN	RF input terminal. The RF signal is input through external matching circuit connected to this terminal. A DC blocking capacitor is not required.
6	GND	Ground terminal.
7	VCTL	Control port. A logic control signal is required to select High or Low gain mode of LNA. This terminal is set to more than +1.8V of logical high level for High gain mode of LNA, and set to –0.3~+0.3V of logical low level for Low gain mode.
8	GND	Ground terminal.

CAUTION

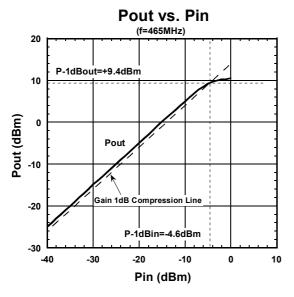
1) Ground terminal (No.2, 4, 6, 8) should be connected to the ground plane as close as possible for excellent RF performance, because distance to GND makes parasitic inductance.

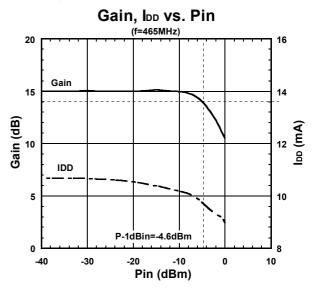
■ TRUTH TABLE

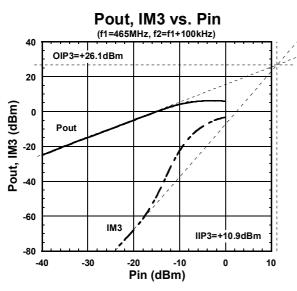
"H"=V_{CTL}(H), "L"=V_{CTL}(L)

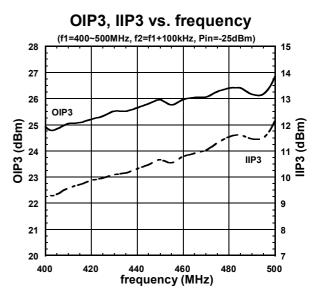
		112(-1);
V _{CTL}	Gain Mode	LNA
L	Low	bypass
Н	High	pass

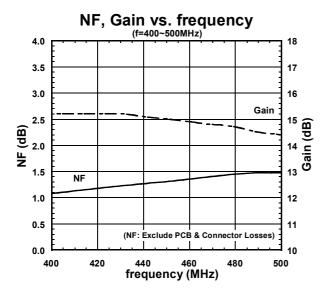
■ ELECTRICAL CHARACTERISTICS (LNA High Gain Mode)



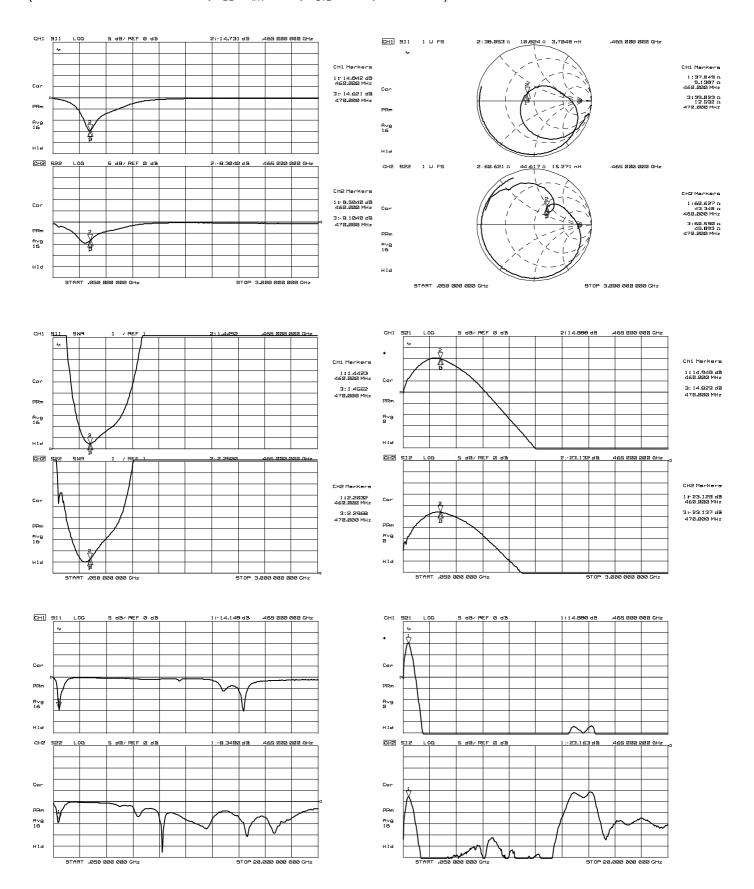




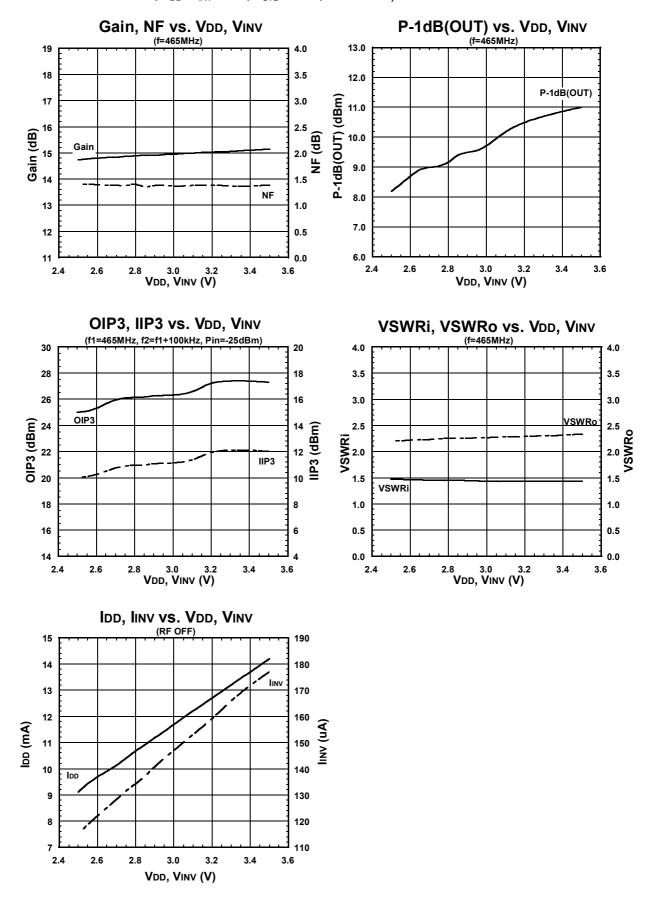




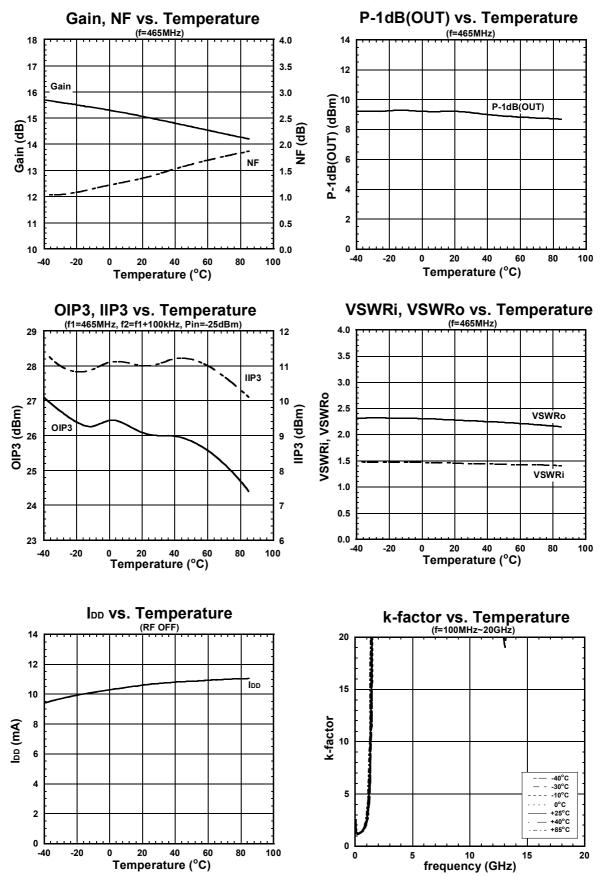
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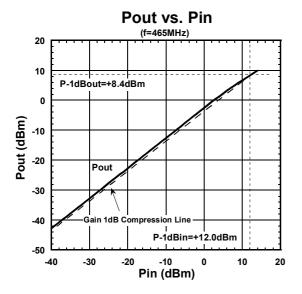
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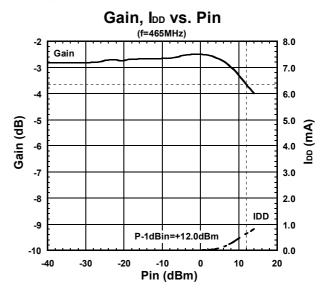


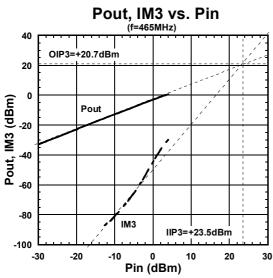
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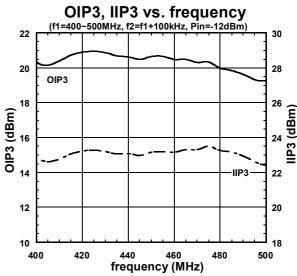


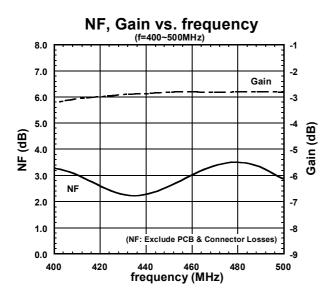
■ ELECTRICAL CHARACTERISTICS (LNA Low Gain Mode)



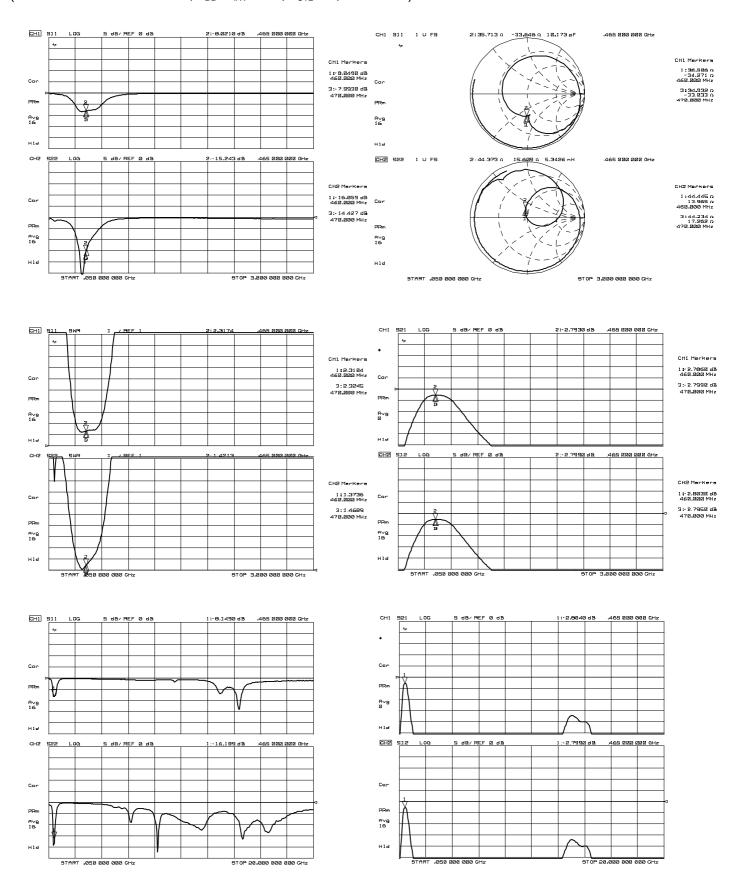




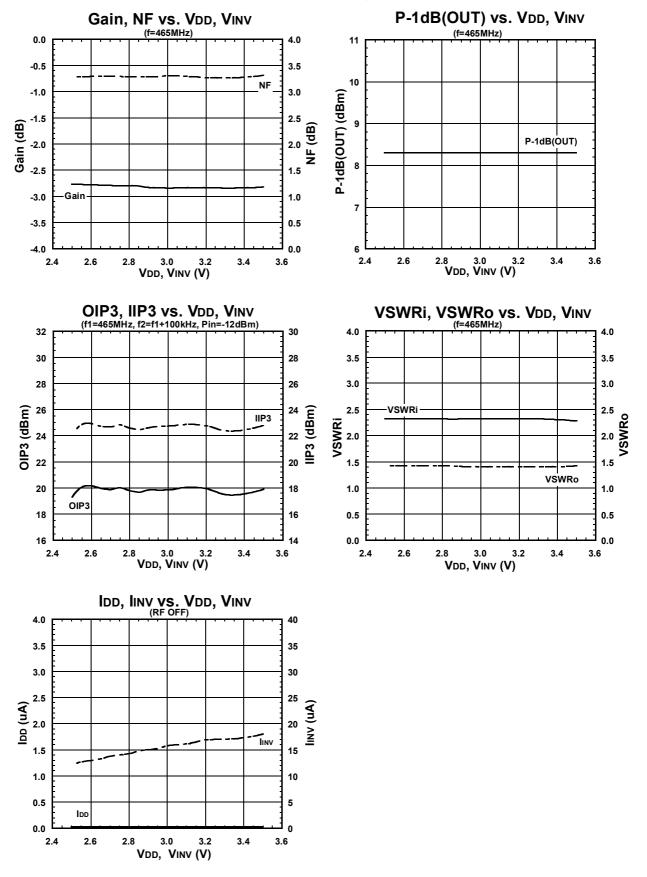




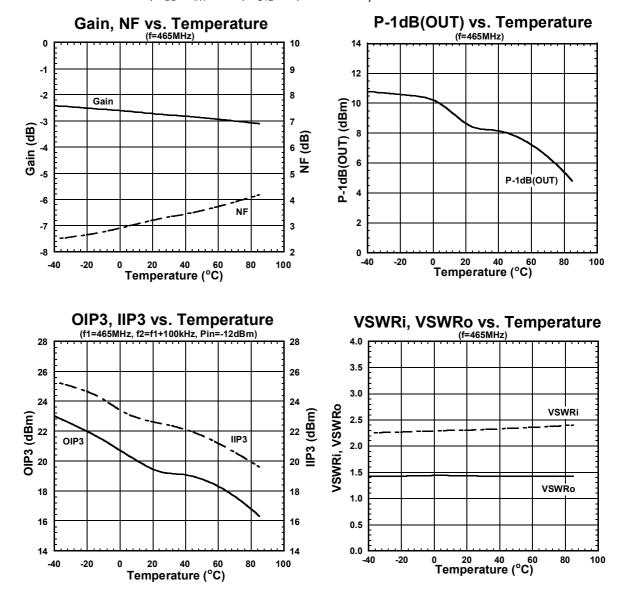
■ ELECTRICAL CHARACTERISTICS (LNA Low Gain Mode)

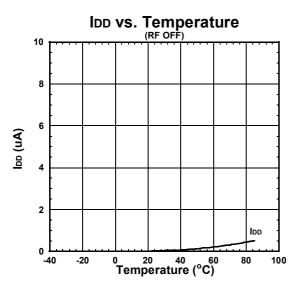


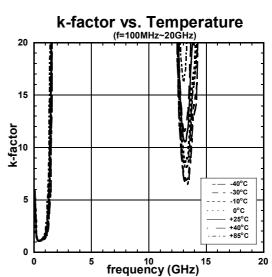
■ ELECTRICAL CHARACTERISTICS (LNA Low Gain Mode)



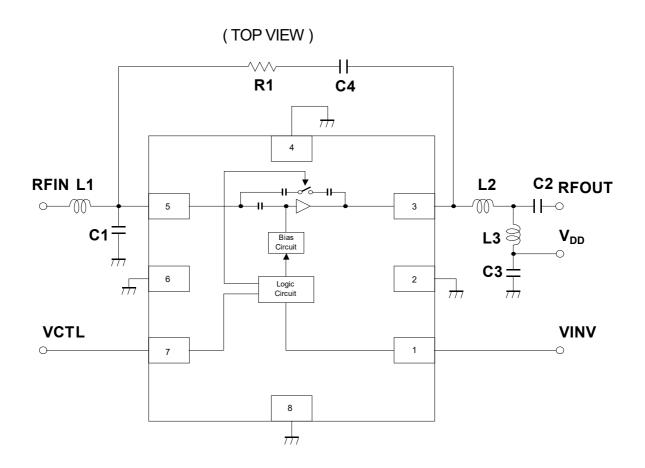
■ ELECTRICAL CHARACTERISTICS (LNA Low Gain Mode)







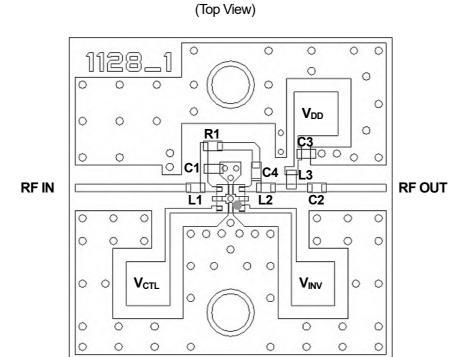
■ APPLICATION CIRCUIT



Parts List

PART ID	CONSTANTS	COMMENT
L1	27nH	MURATA (LQW15A)
L2	33nH	TAIYO-YUDEN (HK1005)
L3	33nH	TAIYO-YUDEN (HK1005)
C1	0.75pF	MURATA (GRM15)
C2	1000pF	MURATA (GRM15)
C3	1000pF	MURATA (GRM15)
C4	2pF	MURATA (GRM15)
R1	2.7kΩ	1005size

■ TEST PCB LAYOUT



PCB(FR-4),t=0.2mm

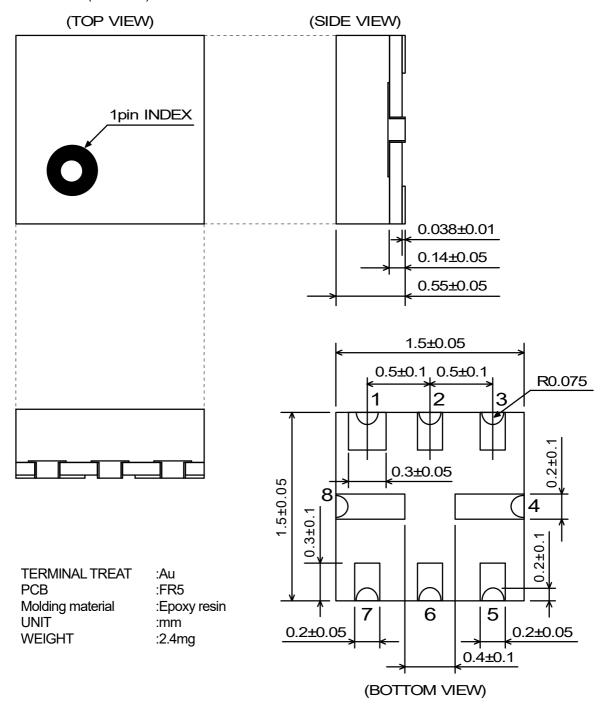
MICROSTRIP LINE WIDTH=0.4mm(Z_0 = 50Ω)

PCB SIZE: 17.0 X 17.0mm

PRECAUTIONS

- [1] C1 and L1 form the input matching circuit. They should be placed close to RFIN terminal (5th pin).
- [2] L2 and L3 form the output matching circuit. They should be placed close to RFOUT terminal (3rd pin).
- [3] R1 and C4 form the negative feedback circuit. The pattern between RFOUT terminal (3rd pin) and RFIN terminal (5th pin) should be designed as short as possible for good performance.
- [4] C2 is a DC-blocking capacitor.
- [5] C3 is a bypass capacitor, it should be placed close to L3.
- [6] Ground terminals(2nd, 4th, 6th and 8th pin) should be connected to ground plane as close as possible for good performance.

■ PACKAGE OUTLINE (USB8-B6)



Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

[CAUTION]

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- 6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
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- 8. Quality Warranty
 - 8-1. Quality Warranty Period
 - In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.
 - 8-2. Quality Warranty Remedies
 - When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.
 - Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
 - 8-3. Remedies after Quality Warranty Period
 - With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.
- 9. Anti-radiation design is not implemented in the products described in this document.
- 10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
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